

Gate Driver Providing Galvanic Isolation Series

Isolation voltage 3750Vrms 1ch Gate Driver Providing Galvanic Isolation

BM61S40RFV-C

General Description

The BM61S40RFV-C is a gate driver with an isolation voltage of 3750 Vrms, I/O delay time of 65ns, and minimum input pulse width of 60ns. It incorporates the Under-Voltage Lockout (UVLO) function, Miller clamp function and Over-Voltage Protect (OVP) function.

Features

- AEC-Q100 Qualified^(Note 1)
- Providing Galvanic Isolation
- Active Miller Clamping
- Under-Voltage Lockout Function
- Over-Voltage Protect Function
- UL1577 Recognized: File E356010 (Note 1) Grade1

Applications

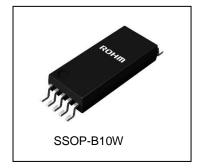
■ SiC MOSFET Gate Drive

Key Specifications

Isolation Voltage: 3750 Vrms
Maximum Gate Drive Voltage: 20 V
I/O Delay Time: 65 ns(Max)
Minimum Input Pulse Width: 60 ns
Output Current 4 A

Package SSOP-B10W

W(Typ) x D(Typ) x H(Max) 3.5 mm x10.2 mm x 1.9 mm



Typical Application Circuits

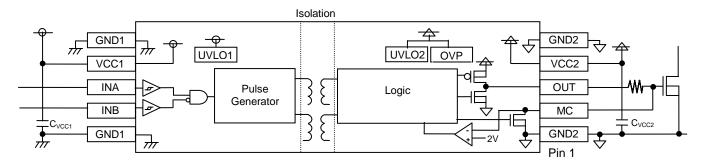


Figure 1. For Driving SiC MOSFET without Negative Power Supply

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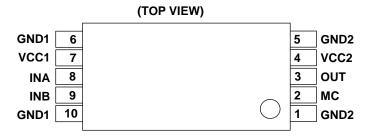
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Recommended Range of External Constants

Din Nama	Cumbal	Recor	mmended	l Value	Lloit
Pin Name	Pin Name Symbol		Тур	Max	Unit
VCC1	C _{VCC1}	0.1	1.0	-	μF
VCC2	C _{VCC2}	0.01	_(Note 2)	-	μF

(Note 2) Value according to the load

Pin Configurations



Pin Descriptions

Pin No.	Pin Name	Function
1	GND2	Output-side ground pin
2	MC	Miller clamp pin
3	OUT	Output pin
4	VCC2	Output-side power supply pin
5	GND2	Output-side ground pin
6	GND1	Input-side ground pin
7	VCC1	Input-side power supply pin
8	INA	Control input A pin
9	INB	Control input B pin
10	GND1	Input-side ground pin

Pin Descriptions - continued

1) VCC1 (Input-side Power Supply Pin)

The VCC1 pin is a power supply pin on the input side. To suppress voltage fluctuations due to the current to drive internal transformers, connect a bypass capacitor between the VCC1 and the GND1 pins.

2) GND1 (Input-side Ground Pin)

The GND1 pin is a ground pin on the input side.

3) VCC2 (Output-side Power Supply Pin)

The VCC2 pin is a power supply pin on the output side. To reduce voltage fluctuations due to OUT pin output current, connect a bypass capacitor between the VCC2 and the GND2 pins.

4) GND2 (Output-side Ground Pin)

The GND2 pin is a ground pin on the output side.

5) INA, INB (Control Input A/B Pin)

The INA and INB pins are used to determine output logic.

INB	INA	OUT
Н	L	L
Н	Н	L
L	L	L
L	Н	Н

6) OUT (Output Pin)

The OUT pin is used to drive the gate of a power device.

7) MC (Miller Clamp Pin)

The MC pin is for preventing the increase in gate voltage due to the Miller current of the power device connected to the OUT pin. If the Miller Clamp function is not used, short-circuit the MC pin to the GND2 pin.

Description of Functions and Examples of Constant Setting

1) Miller Clamp Function When the INA=L or INB=H and OUT pin voltage < V_{MCON} (typ 2V), the internal MOSFET of the MC pin is turned ON.

INA	INB	MC	Internal MOSFET of the MC Pin
L	X	Less Than V _{MCON}	ON
Х	Н	Less Than V _{MCON}	ON
Н	L	Х	OFF

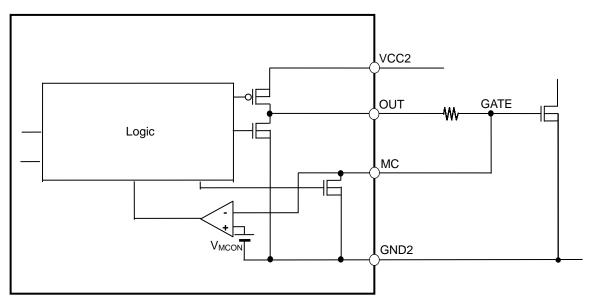


Figure 2. Block Diagram of Miller Clamp Function

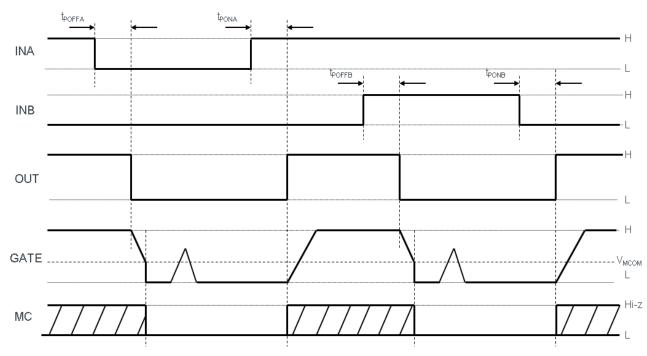


Figure 3. Timing Chart of Miller Clamp Function

Description of Functions and Examples of Constant Setting - continued

2) Under-Voltage Lockout (UVLO) Function

The BM61S40RFV-C incorporates the Under-Voltage Lockout (UVLO) function both on the Input-side and the output-side. When the power supply voltage drops to the UVLO ON voltage (input-side typ 4.0 V, output-side 14.5 V), the OUT pin will output the "L" signal. In addition, to prevent malfunctions due to noises, a mask time of t_{UVLO1MSK} (typ 1.5 µs) and t_{UVLO2MSK} (typ 2.9 µs) are set on both the input-side and the output-side. After the UVLO on Input-side is released, the input signal will take effect from the time after the input signal switches.

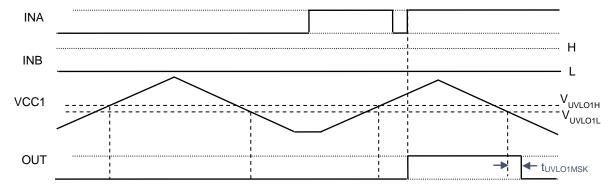


Figure 4. Timing Chart of Input-side UVLO Function

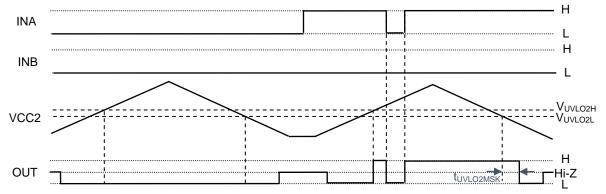


Figure 5. Timing Chart of Output-side UVLO Function

Description of Functions and Examples of Constant Setting - continued

3) Over-Voltage Protect (OVP) Function

The BM61S40RFV-C incorporates the Over-Voltage Protect (OVP) function on the output-side. When the power supply voltage exceeds the OVP ON voltage (typ 21.5 V), the OUT pin will output the "L" signal. In addition, to prevent malfunctions due to noises, a mask time of t_{OVPMSK} (typ 10 μ s) is set. After the OVP is released, OUT pin becomes the logic according to the input logic

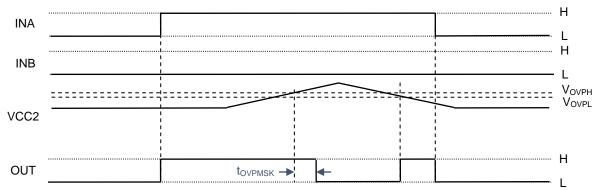


Figure 6. Timing Chart of OVP Function

4) I/O Condition Table

			Output				
No.	Status	VCC1	VCC2	INB	INA	OUT	МС
1	VCC1 UVLO	UVLO	Х	Х	Х	L	L
2	VCC2 UVLO	Х	UVLO	Х	Х	L	L
3	VCC2 OVP	Х	OVP	Х	Х	L	L
4	INB Active	No UVLO	No UVLO No OVP	Н	Х	L	L
5	Normal Operation L Input	No UVLO	No UVLO No OVP	L	L	L	L
6	Normal Operation H input	No UVLO	No UVLO No OVP	L	Н	Н	Hi-Z

X: Don't care

Absolute Maximum Ratings

Parameter	Symbol	Limits	Unit
Input-side Supply Voltage	V _{CC1}	-0.3 to +7.0 ^(Note 3)	V
Output-side Supply Voltage	V _{CC2}	-0.3 to +30.0 ^(Note 4)	V
INA Pin Input Voltage	V _{INA}	-0.3 to +VCC1+0.3 or +7.0 ^(Note 3)	V
INB Pin Input Voltage	V _{INB}	-0.3 to +VCC1+0.3 or +7.0 ^(Note 3)	V
OUT Pin Output Current (Peak 10µs)	I _{OUTPEAK}	self limited	А
Storage Temperature Range	Tstg	-55 to +150	°C
Maximum Junction Temperature	Tjmax	+150	°C

⁽Note 3) Relative to GND1.

Thermal Resistance (Note 5)

Demonstra	0 1 1	Thermal Res		
Parameter	Symbol	1s ^(Note 7)	2s2p ^(Note 8)	Unit
SSOP-B10W				
Input-side Junction to Ambient	θ_{JA1}	172.1	101.8	°C/W
Output-side Junction to Ambient	θ _{JA2}	180.2	108.9	°C/W
Input-side Junction to Top Characterization Parameter ^(Note 6)	Ψ_{JT1}	32	27	°C/W
Output-side Junction to Top Characterization Parameter ^(Note 6)	Ψ_{JT2}	82	60	°C/W

⁽Note 5) Based on JESD51-2A (Still-Air)

Layer Number of

Footprints and Traces

surface of the component package. (Note 7) Using a PCB board based on JESD51-3. (Note 8) Using a PCB board based on JESD51-7.

Layer Number of Measurement Board	Material	Board Size
Single	FR-4	114.3 mm x 76.2 mm x 1.57 mmt
Тор		
Copper Pattern	Thickness	
Footprints and Traces	70 µm	

Material

70 µm

Measurement Board	Materiai	Board Size			
4 Layers	FR-4	114.3 mm x 76.2 mm	x 1.6 mmt		
Тор		2 Internal Laye	ers	Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness

74.2 mm x 74.2 mm

Board Size

35 µm

74.2 mm x 74.2 mm

70 µm

⁽Note 4) Relative to GND2.

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB boards with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.

⁽Note 6) The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside

Recommended Operating Ratings

Parameter	Symbol	Min	Max	Units
Input-side Supply Voltage	V _{CC1} ^(Note 9)	4.5	5.5	V
Output-side Supply Voltage	V _{CC2} ^(Note 10)	16	20	V
Operating Temperature	Topr	-40	125	°C

(Note 9) Relative to GND1. (Note 10) Relative to GND2.

Insulation Related Characteristics

Basic Insulation Requirements according to VDE0884-11(pending)

Parameter	Symbol	Characteristic	Units
Insulation Classification Per EN 60664-1, Table 1 For Rated Main Voltage< 150Vrms For Rated Main Voltage< 300Vrms For Rated Main Voltage< 450Vrms		Rated Impulse Voltage I - IV I - IV I - III	-
For Rated Main Voltage< 600Vrms		1 - 111	
Climatic Classification		40/125/21	-
Pollution Decree(EN 60664-1)		2	-
Minimum External Clearance	CLR	8.1	mm
Minimum External Creepage	CPG	8.1	mm
Minimum Internal Gap (Internal Clearance)		0.012	mm
Minimum Comparative Tracking Index	СТІ	>400	-
Minimum Repetitive Insulation Voltage	V _{IORM}	891	
Input to Output Test Voltage, Method b VIORM * 1.875= VPR, Productive Test, tm = 1s, Partial Discharge < 5pC	V _{PR}	1671	V_{peak}
Surge Isolation Voltage	V _{IOSM}	6000	
Highest Allowable Voltage, 1min	V _{IOTM}	5300	
Insulation Resistance at T _S , VIO = 500V	R _{IO}	>10 ⁹	Ω

Recognized under UL 1577

Description	Symbol	Characteristic	Units
Insulation Withstand Voltage / 1min	V _{ISO}	3750	Vrms
Insulation Test Voltage / 1s	V _{ISO}	4500	Vrms

UL1577 Ratings TableFollowing values are described in UL Report.

Parameter	Values	Units	Conditions
Side 1 (Input Side) Circuit Current	0.4	mA	VCC1=5.0V, OUT=L
Side 2 (Output Side) Circuit Current	0.7	mA	VCC2=15V, OUT=L
Side 1 (Input Side) Consumption Power	2	mW	VCC1=5.0V, OUT=L
Side 2 (Output Side) Consumption Power	12.6	mW	VCC2=15V, OUT=L
Isolation Voltage	3750	Vrms	
Maximum Operating (Ambient) Temperature	125	°C	
Maximum Junction Temperature	150	°C	
Maximum Storage Temperature	150	°C	
Maximum Data Transmission Rate	8.33	MHz	

Electrical Characteristics

(Unless otherwise specified Ta=-40°C to +125°C, V_{CC1}=4.5V to 5.5V, V_{CC2}=16V to 20V)

(Unless otherwise specified Ta=-4						
Parameter	Symbol	Min	Тур	Max	Unit	Conditions
General Input-side Circuit Current 1	I _{CC11}	0.2	0.4	1.0	mA	INA=L,INB=H
Input-side Circuit Current 2		1.0	2.0	4.0	mA	INA=100kHz, Duty=50%
•	I _{CC12}		1		_	· · · · · · · · · · · · · · · · · · ·
Output-side Circuit Current 1	I _{CC21}	0.30	0.70	1.20	mA	OUT=L
Output-side Circuit Current 2	I _{CC22}	0.22	0.52	0.90	mA	OUT=H
Logic Block	.,					INIA INID
Logic High Level Input Voltage	V _{INH}	2.0	-	V _{CC1}	V	INA, INB
Logic Low Level Input Voltage	V_{INL}	0	-	0.8	V	INA, INB
Logic Pull-down Resistance	R _{IND}	25	50	100	kΩ	INA
Logic Pull-up Resistance	R _{INU}	25	50	100	kΩ	INB
Logic Input Minimum Pulse Width	t _{INMIN}	60	-	-	ns	INA, INB
Output						
OUT ON Resistance (Source)	Ronh	0.3	0.67	1.5	Ω	I _{OUT} =-40mA
OUT ON Resistance (Sink)	R _{ONL}	0.15	0.45	0.98	Ω	I _{OUT} =40mA
OUT Maximum Current (Source)	I _{OUTMAXH}	4.0	-	-	Α	VCC2=18 V, Guaranteed by Design
OUT Maximum Current (Sink)	IOUTMAXL	4.0	-	-	Α	VCC2=18 V, Guaranteed by Design
T ON T	t _{PONA}	45	55	65	ns	INA=PWM, INB=L
Turn ON Time	t _{PONB}	45	55	65	ns	INA=H, INB=PWM
	t _{POFFA}	45	55	65	ns	INA=PWM, INB=L
Turn OFF Time	t _{POFFB}	45	55	65	ns	INA=H, INB=PWM
	t _{PDISTA}	-10	0	+10	ns	t _{POFFA} – t _{PONA}
Propagation Distortion	t _{PDISTB}	-10	0	+10	ns	t _{POFFB} – t _{PONB}
Part to Part Skew	Tsk-pp	-	-	20	ns	10115 10115
Rise Time	t _{RISE}	_	15	-	ns	2 nF between OUT-GND2
Fall Time	t _{FALL}		15	_	ns	2 nF between OUT-GND2
MC ON Resistance	R _{ONMC}	0.15	0.45	0.98	Ω	I _{MC} =40 mA
MC ON Threshold Voltage	1	1.8	2	2.2	V	IMC=40 III/ (
-	V _{MCON}					Guaranteed by Design
Common Mode Transient Immunity	CM	100	-	-	kV/μs	Guaranteed by Design
Protection Functions	1	2.05	4.0	4.45	17	
V _{CC1} UVLO OFF Voltage	V _{UVLO1H}	3.95	4.2	4.45	V	
V _{CC1} UVLO ON Voltage	V_{UVLO1L}	3.75	4.0	4.25	V	
V _{CC1} UVLO Mask Time	t _{UVLO1MSK}	0.4	1.5	5.0	μs	
V _{CC2} UVLO OFF Voltage	V_{UVLO2H}	14.6	15.0	15.4	V	
V _{CC2} UVLO ON Voltage	V_{UVLO2L}	14.1	14.5	14.9	V	
V _{CC2} UVLO Mask Time	t _{UVLO2MSK}	1.0	2.9	5.0	μs	
V _{CC2} OVP OFF Voltage	V_{OVPL}	20.6	21.0	21.4	V	
V _{CC2} OVP ON Voltage	V_{OVPH}	21.1	21.5	21.9	V	
V _{CC2} OVP Mask Time	t _{OVPMSK}	3.0	10.0	20.0	μs	

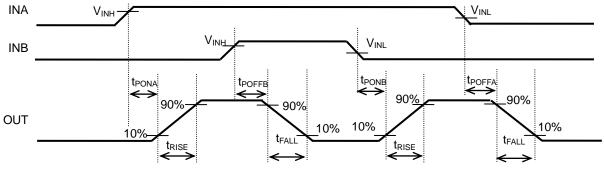


Figure 7. Timing Chart of IN-OUT

Typical Performance Curves

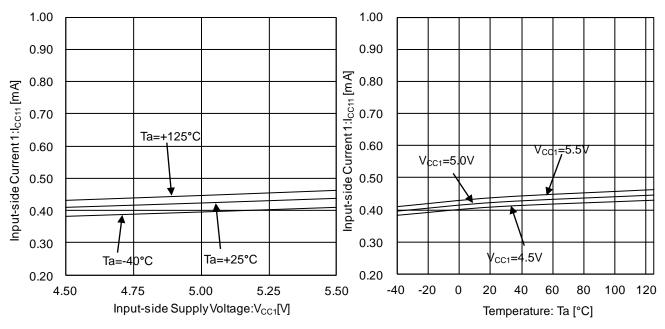


Figure 8. Input-side Circuit Current 1 vs Input-side Supply Voltage

Figure 9. Input-side Circuit Current 1 vs Temperature

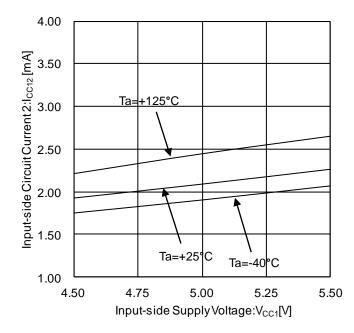


Figure 10. Input-side Circuit Current 2 vs Input-side Supply Voltage (At INA=100 kHz, Duty=50 %)

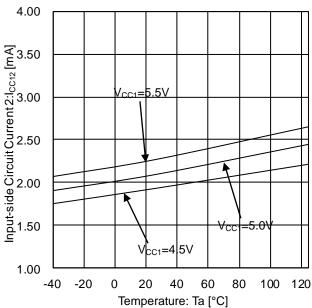


Figure 11. Input-side Circuit Current 2 vs Temperature (At INA=100 kHz, Duty=50 %)

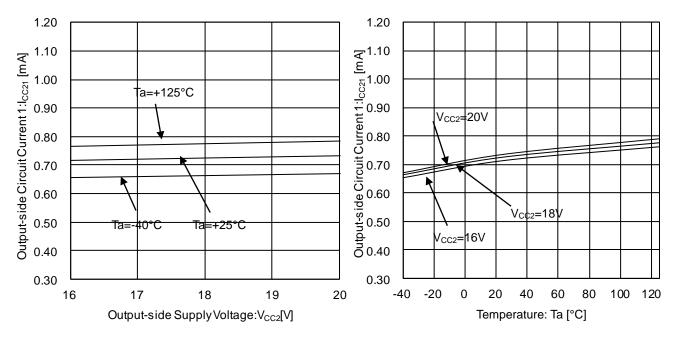


Figure 12. Output-side Circuit Current 1 vs Output-side Supply Voltage (At OUT=L)

Figure 13. Output-side Circuit Current 1 vs Temperature (At OUT=L)

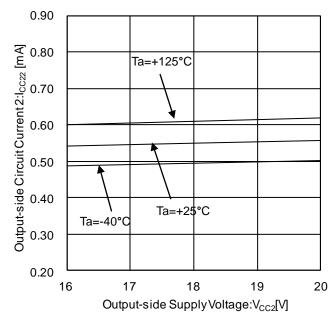


Figure 14.Output-side Circuit Current 2 vs Output-side Supply Voltage (At OUT=H)

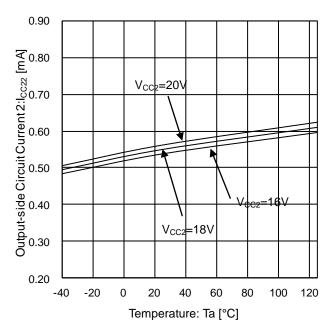


Figure 15 Output-side Circuit Current 2 vs Temperature (At OUT=H)

BM61S40RFV-C

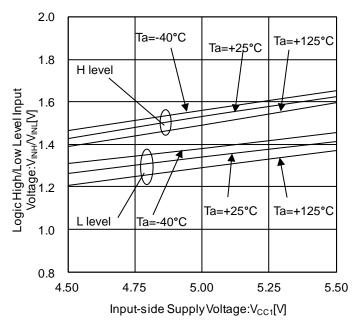


Figure 16. Logic High/Low Level Input Voltage vs Input-side Supply Voltage

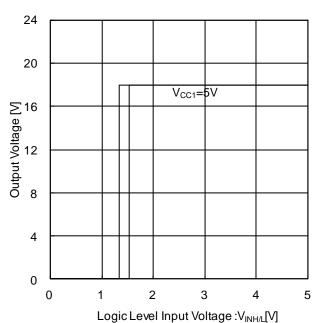


Figure 17.Output Voltage vs Logic Level Input Voltage (INA) (V_{CC1}=5 V, V_{CC2}=18 V, Ta=25 °C)

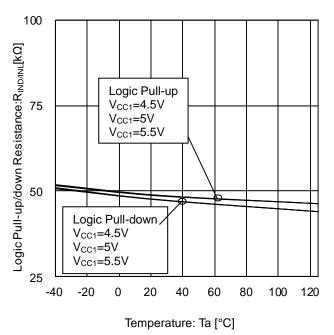


Figure 18 Logic Pull-up/down Resistance vs Temperature

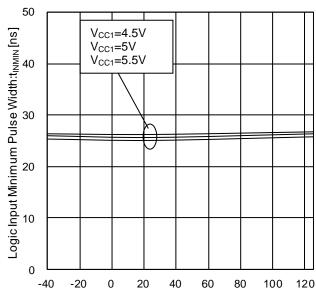


Figure 19 Logic Input Minimum Pulse Width vs Temperature

Temperature: Ta [°C]

BM61S40RFV-C Datasheet

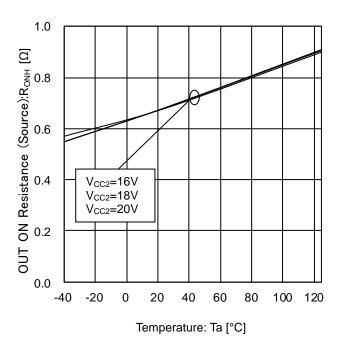


Figure 20. OUT ON Resistance (Source) vs Temperature

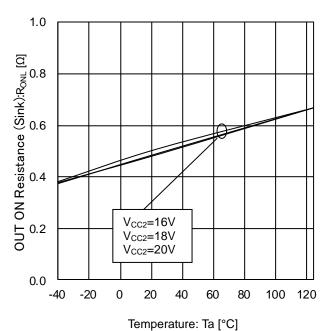


Figure 21. OUT ON Resistance (Sink) vs Temperature

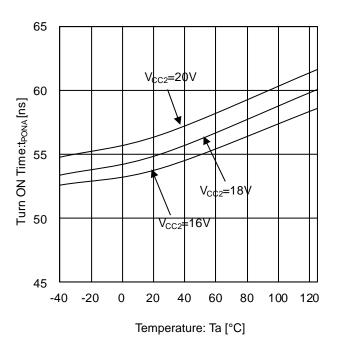


Figure 22 Turn ON Time vs Temperature (INA=PWM, INB=L)

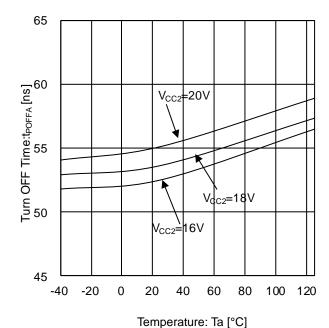


Figure 23 Turn OFF Time vs Temperature (INA=PWM, INB=L)

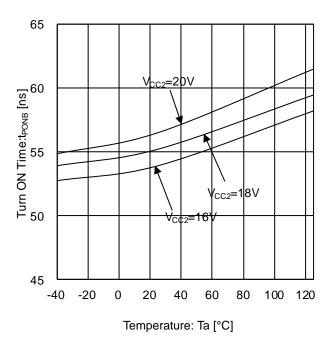


Figure 24. Turn ON Time vs Temperature (INA=H, INB=PWM)

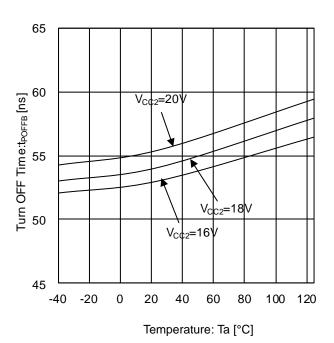


Figure 25. Turn OFF Time vs Temperature (INA=H, INB=PWM)

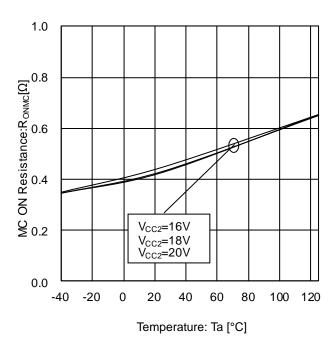


Figure 26. MC ON Resistance vs Temperature

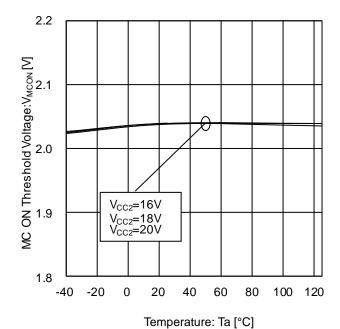


Figure 27. MC ON Threshold Voltage vs Temperature

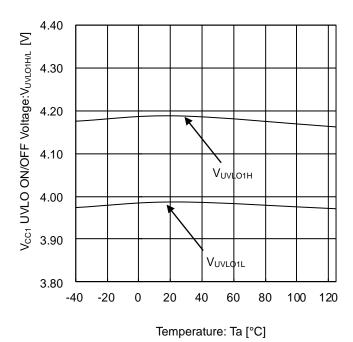


Figure 28 V_{CC1} UVLO ON/OFF Voltage vs Temperature

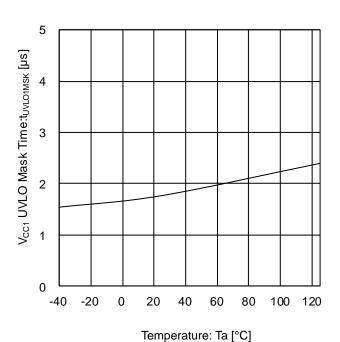


Figure 29 V_{CC1} UVLO Mask Time vs Temperature

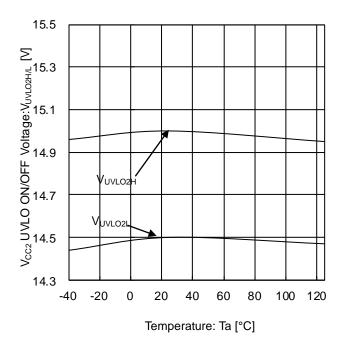


Figure 30 V_{CC2} UVLO ON/OFF Voltage vs Temperature

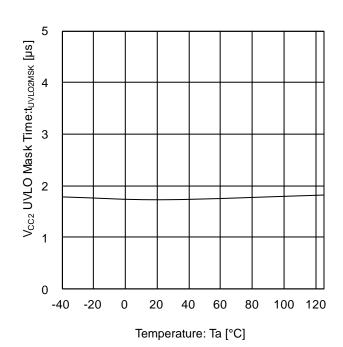


Figure 31 V_{CC2} UVLO Mask Time vs Temperature

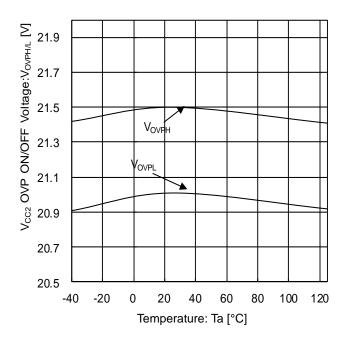


Figure 32 V_{CC2} OVP ON/OFF Voltage vs Temperature

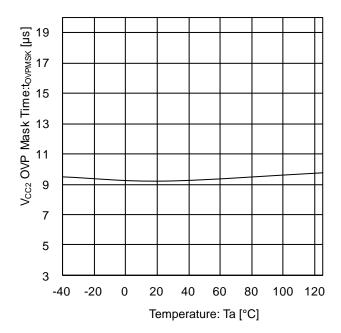


Figure 33 V_{CC2} OVP Mask Time vs Temperature

Selection of Components Externally Connected

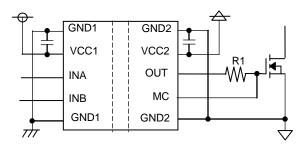


Figure 34. Driving SiC MOSFET

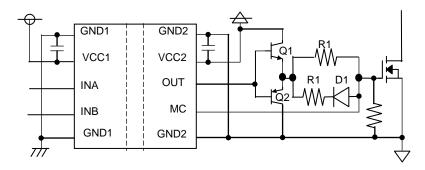


Figure 35. Driving SiC MOSFET with Buffer Circuit

Recommended Parts

	Manufacturer	Element	Part Number
R1	R1 ROHM Resistor LTR18EZP,LTR50UZP		LTR18EZP,LTR50UZP
Q1	ROHM	NPN Transistor	2SCR542PFRA
Q2	ROHM	PNP Transistor	2SAR542PFRA
D1	ROHM	Diode	RBR3MM30ATF,RBR5LAM30ATF

I/O Equivalence Circuits

	Name				
Pin No.	Function	I/O Equivalence Circuits			
1	OUT	VCC2 OUT			
·	Output Pin	GND2			
	MC	VCC2			
2	Miller Clamp pin	MC GND2			
3	INA	VCC1 O			
3	Control Input pin A	GND1 O			
4	INB	VCC1 O			
	Control Input pin B	GND1 GND1			

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Separate the ground and supply lines of the digital and analog blocks to prevent noise in the ground and supply lines of the digital block from affecting the analog block. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

8. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

9. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

Operational Notes - continued

10. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

11. Regarding the Input Pin of the IC

This IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.

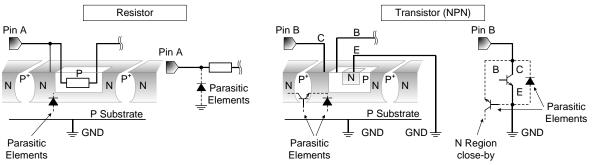
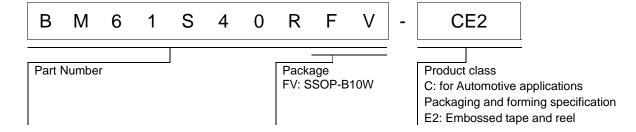


Figure 36. Example of IC structure

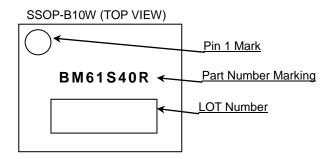
12. Ceramic Capacitor

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

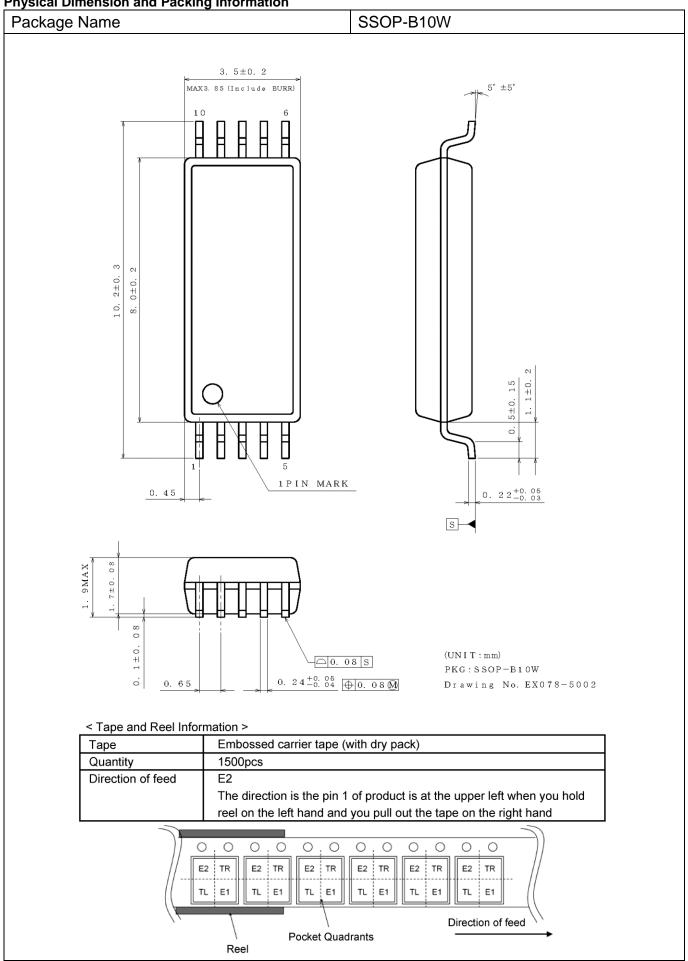
Ordering Information



Marking Diagram



Physical Dimension and Packing Information



Revision History

icion microry					
Date Revision		Changes			
14.May.2018	001	New Release			
30.Mar.2020	002	Page 1: Changed Features Before: UL1577(pending) → After: UL1577 Recognized Page 9: Corrected Insulation Related Characteristic Before: Reinforced Insulation → After: Basic Insulation Before: VDE0884-10(pending) → After: VDE0884-11(pending) Before: Recognized under UL 1577(pending) → After: Recognized under UL 1577 Before: V _{pk} → After: V _{peak} Corrected Highest Allowable Voltage, 1min Before: 3750Vrms → After: 5300V _{peak} Page 10: Added UL1577 Rating Table			

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ſ	JÁPAN	USA	EU	CHINA
Ī	CLASSⅢ	CLASSIII	CLASS II b	СГУССШ
ſ	CLASSIV		CLASSⅢ	CLASSⅢ

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 - [h] Use of the Products in places subject to dew condensation
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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